

## FJ6K01010L

### Silicon P-channel MOS FET

For switching

#### ■ Features

- Low drain-source On-state resistance :  $R_{DS(on)}$  typ. =  $26\text{ m}\Omega$  (  $V_{GS} = -4.5\text{ V}$  )
- Low drive voltage :  $1.8\text{ V}$  drive
- Halogen-free / RoHS compliant  
(EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

#### ■ Marking Symbol : T4

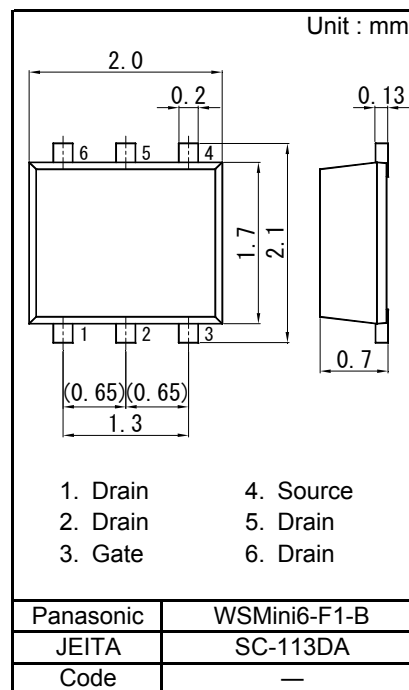
#### ■ Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

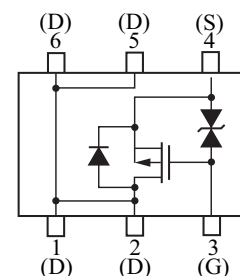
#### ■ Absolute Maximum Ratings $T_a = 25\text{ }^{\circ}\text{C}$

| Parameter                             | Symbol    | Rating      | Unit               |
|---------------------------------------|-----------|-------------|--------------------|
| Drain-source voltage                  | $V_{DS}$  | -12         | V                  |
| Gate-source voltage                   | $V_{GS}$  | $\pm 8$     | V                  |
| Drain current                         | $I_D$     | -4.0        | A                  |
| Pulse drain current                   | $I_{Dp}$  | -20         | A                  |
| Total power dissipation <sup>*1</sup> | PD        | 700         | mW                 |
| Channel temperature                   | $T_{ch}$  | 150         | $^{\circ}\text{C}$ |
| Operating ambient temperature         | $T_{opr}$ | -40 to + 85 | $^{\circ}\text{C}$ |
| Storage temperature                   | $T_{stg}$ | -55 to +150 | $^{\circ}\text{C}$ |

Note) <sup>\*1</sup> Measuring on Glass epoxy board (25.4 x 25.4 x 0.8 mm) (See Figure 1)  
Absolute maximum rating without heat sink for PD is 150 mW

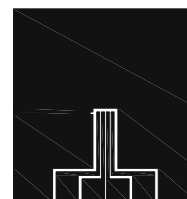


#### Internal Connection



#### Pin Name

1. Drain      4. Source  
2. Drain      5. Drain  
3. Gate      6. Drain



**Figure 1** FR4 Glass-Epoxy Board  
25.4 mm × 25.4 mm × 0.8 mm

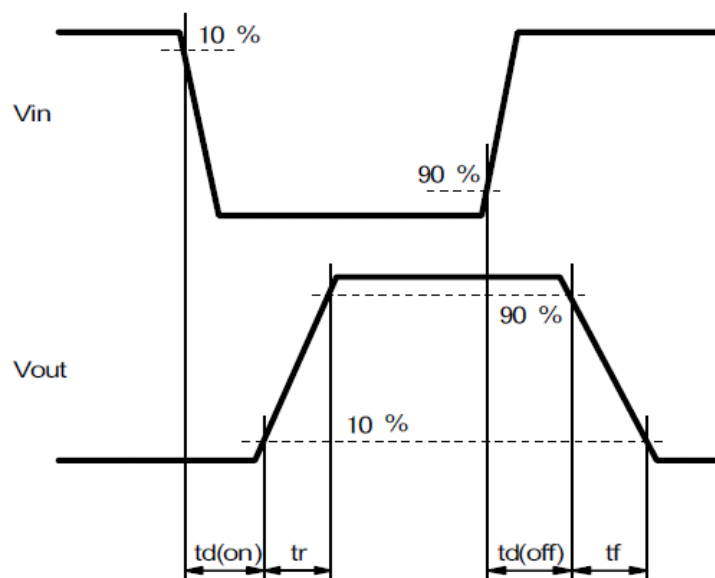
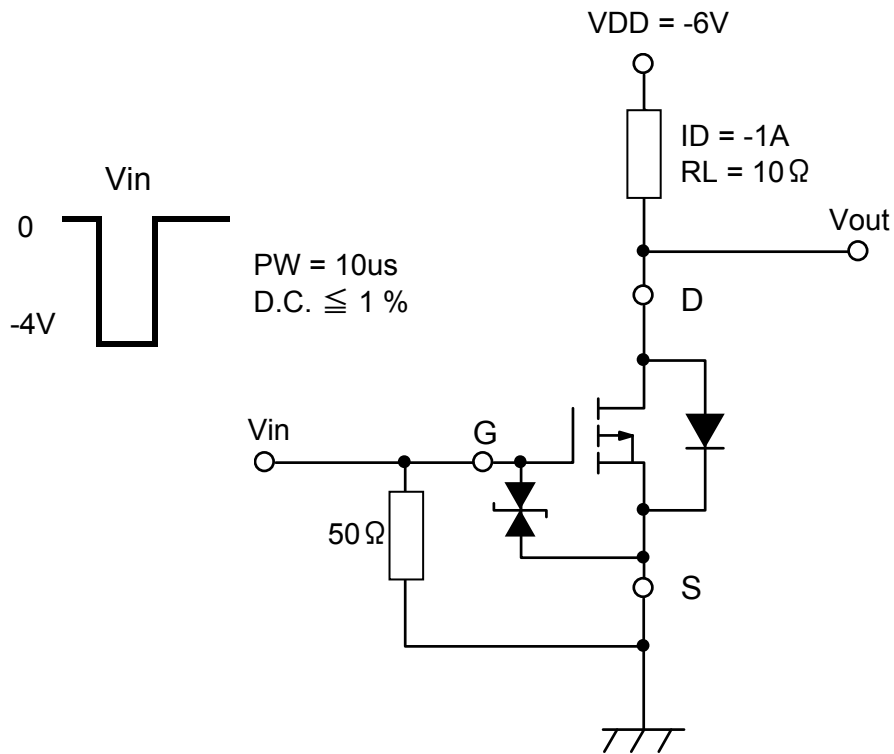
■ Electrical Characteristics Ta = 25 °C ± 3 °C

| Parameter                         | Symbol   | Conditions                      | Min  | Typ   | Max  | Unit |
|-----------------------------------|----------|---------------------------------|------|-------|------|------|
| Drain-source breakdown voltage    | VDSS     | ID = -1 mA, VGS = 0             | -12  |       |      | V    |
| Drain-source cutoff current       | IDSS     | VDS = -10 V, VGS = 0            |      |       | -1.0 | μA   |
| Gate-source cutoff current        | IGSS     | VGS = ±8 V, VDS = 0             |      |       | ±10  | μA   |
| Gate threshold voltage            | Vth      | ID = -1.0 mA, VDS = -6.0 V      | -0.3 | -0.65 | -1.0 | V    |
| Drain-source ON resistance        | RDS(on)1 | ID = -1.0 A, VGS = -4.5 V       |      | 26    | 34   | mΩ   |
|                                   | RDS(on)2 | ID = -0.5 A, VGS = -2.5 V       |      | 30    | 41   |      |
|                                   | RDS(on)3 | ID = -0.5 A, VGS = -1.8 V       |      | 36    | 54   |      |
| Forward transfer admittance       | Yfs      | ID = -1.0 A, VDS = -10 V        | 4.0  |       |      | S    |
| Input capacitance                 | Ciss     | VDS = -10 V, VGS = 0, f = 1 MHz |      | 1 400 |      | pF   |
| Output capacitance                | Coss     |                                 |      | 190   |      | pF   |
| Reverse transfer capacitance      | Crss     |                                 |      | 210   |      | pF   |
| Turn-on delay time <sup>*1</sup>  | td(on)   | VDD = -6 V, VGS = 0 to -4 V     |      | 9     |      | ns   |
| Rise time <sup>*1</sup>           | tr       | ID = -1.0 A                     |      | 40    |      | ns   |
| Turn-off delay time <sup>*1</sup> | td(off)  | VDD = -6 V, VGS = -4 to 0 V     |      | 250   |      | ns   |
| Fall time <sup>*1</sup>           | tf       | ID = -1.0 A                     |      | 150   |      | ns   |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

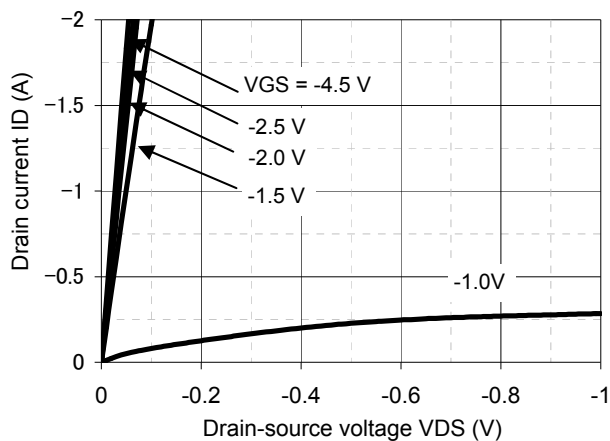
2. \*1 Measurement circuit for Turn-on Delay Time/Rise Time/Turn-off Delay Time/Fall Time

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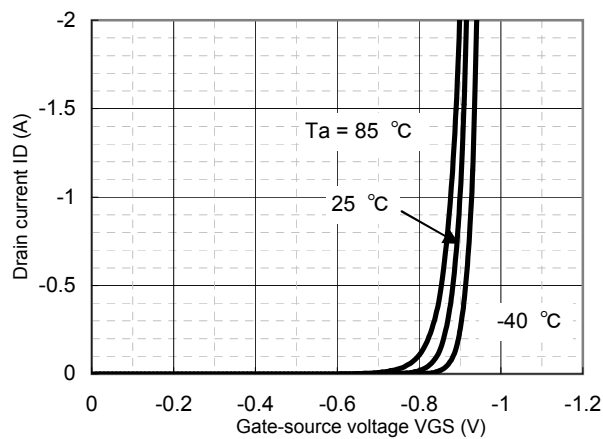


Technical Data ( reference )

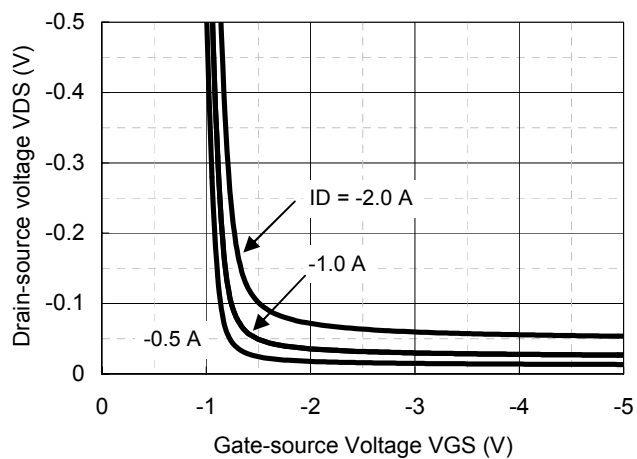
ID - VDS



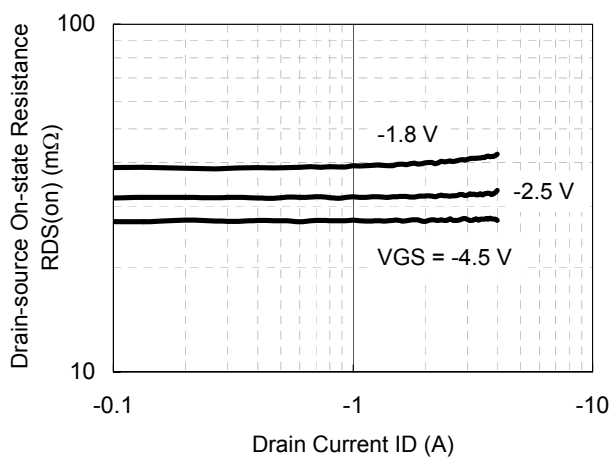
ID - VGS



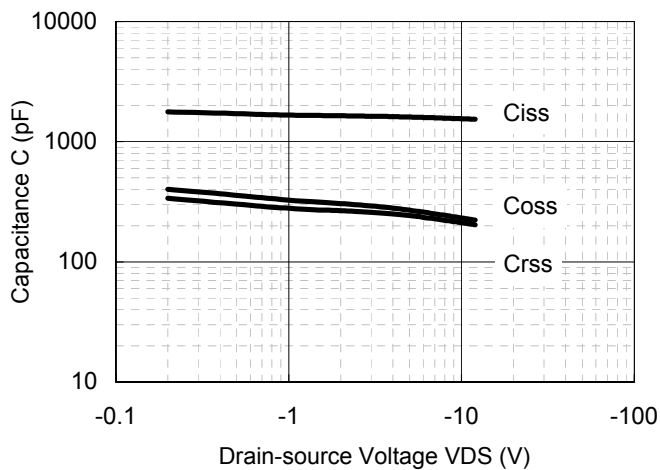
VDS - VGS



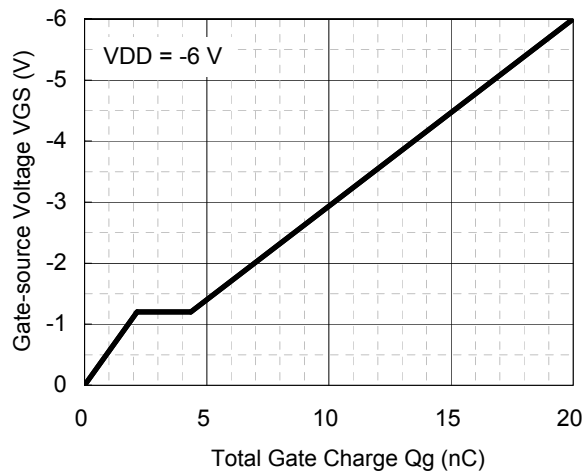
RDS(on) - ID



Capacitance - VDS

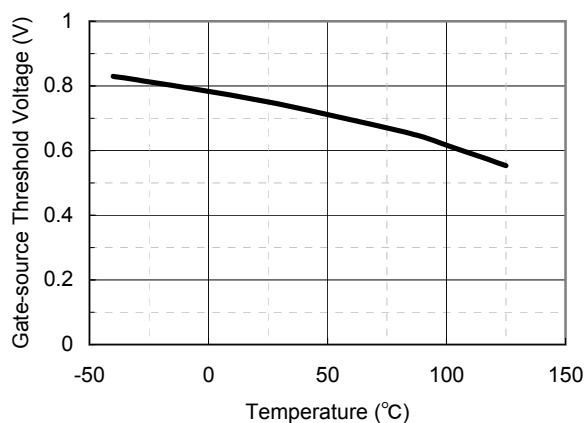


Dynamic Input/Output Characteristics

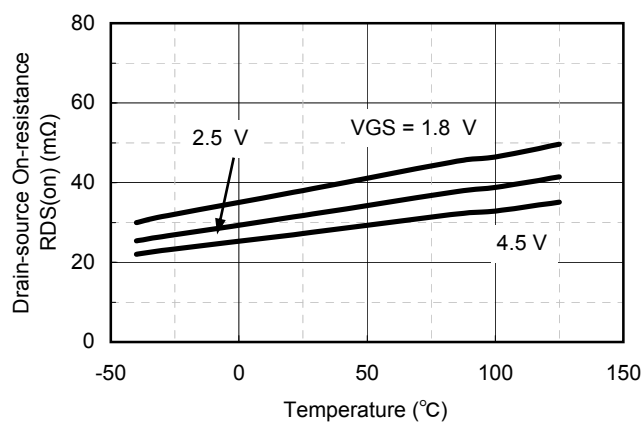


# Technical Data ( reference )

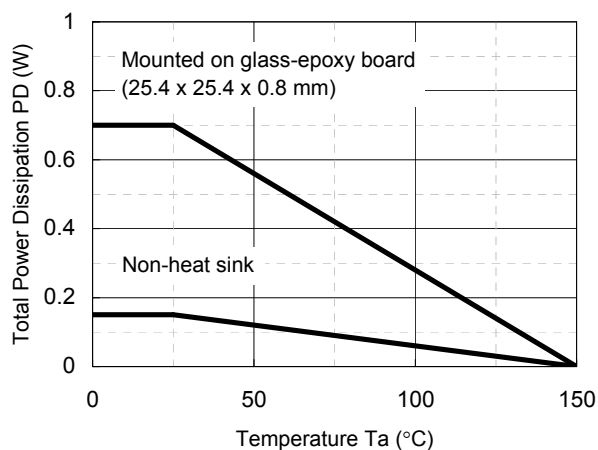
V<sub>th</sub> - T<sub>a</sub>



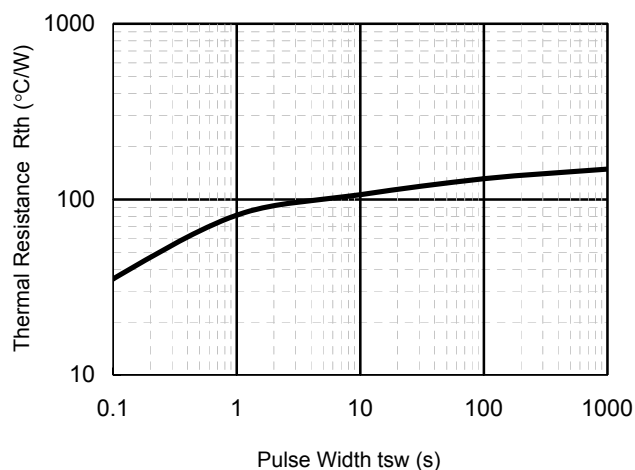
R<sub>DS(on)</sub> - T<sub>a</sub>



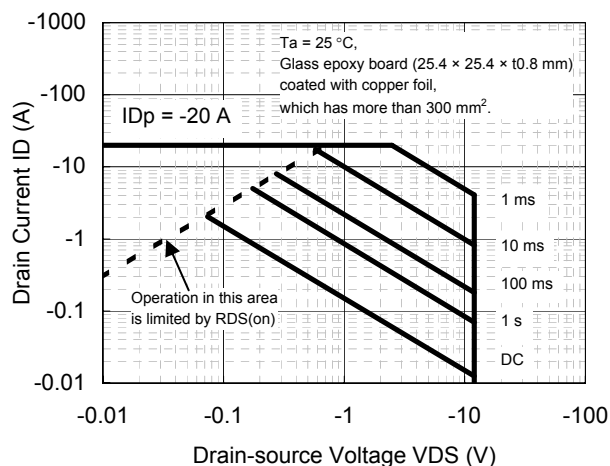
P<sub>D</sub> - T<sub>a</sub>



R<sub>th</sub> - t<sub>sw</sub>



Safe Operating Area

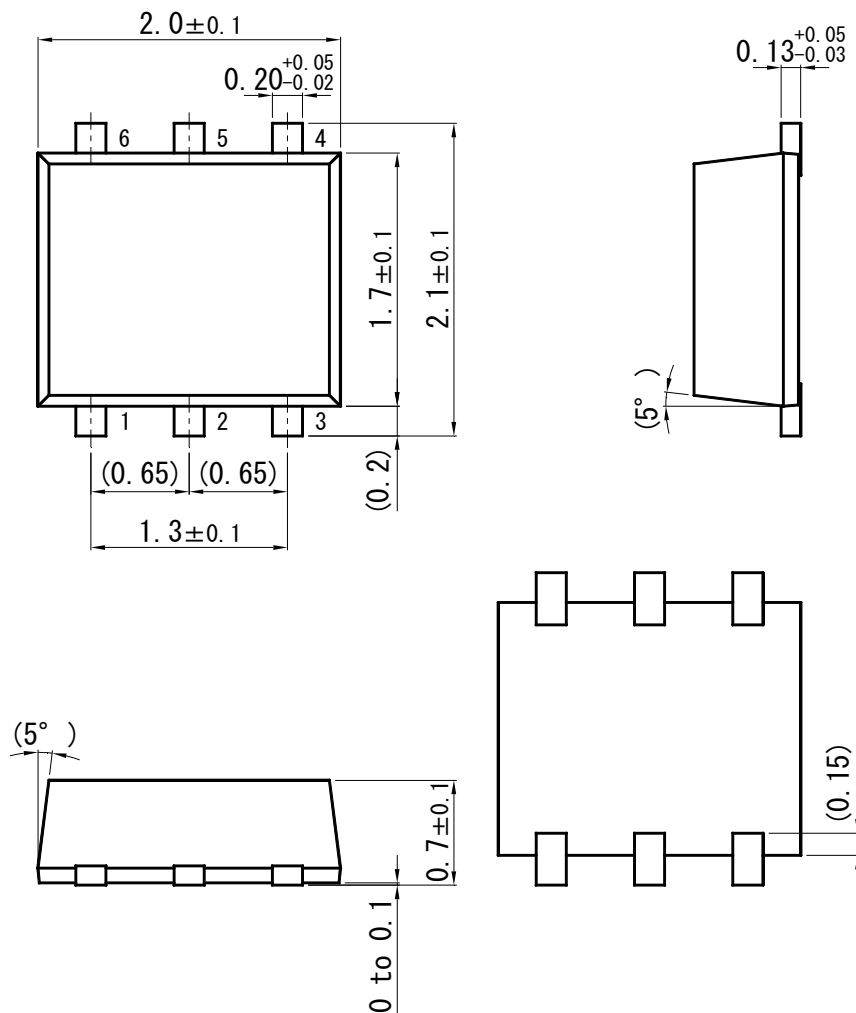


**Panasonic**

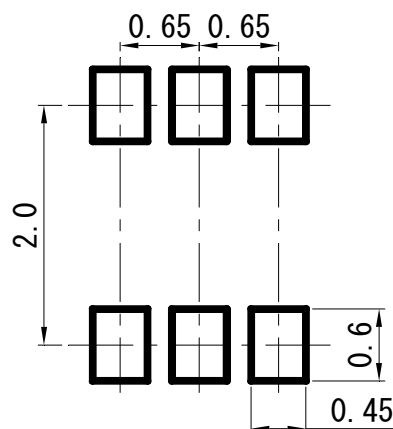
MOS FET  
FJ6K01010L

WSMini6-F1-B

Unit : mm



■ Land Pattern (Reference) (Unit : mm)



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